TOSHIBA Transistor Silicon NPN Triple Diffused Mesa Type

2SC5355

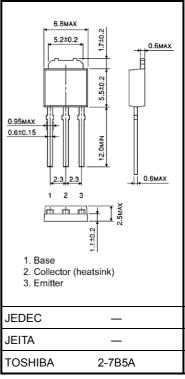
High Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications

- Excellent switching times: $t_r = 0.5 \mu s$ (max), $t_f = 0.3 \mu s$ (max)
- High collector breakdown voltage: VCEO = 400 V
- High DC current gain: hFE = 20 (min)

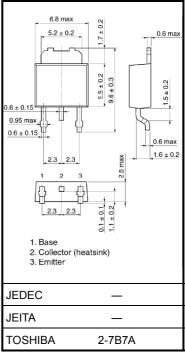
Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit | |
|-----------------------------|-----------|------------------|---------|------|--|
| Collector-base voltage | | V_{CBO} | 600 | V | |
| Collector-emitter voltage | | V _{CEO} | 400 | V | |
| Emitter-base voltage | | V _{EBO} | 7 | V | |
| Collector current | DC | Ic | 5 | А | |
| | Pulse | I _{CP} | 7 | | |
| Base current | | Ι _Β | 1 | Α | |
| Collector power dissipation | Ta = 25°C | Pc | 1.5 | W | |
| | Tc = 25°C | FC | 25 | | |
| Junction temperature | | Tj | 150 | °C | |
| Storage temperature range | | T _{stg} | -55~150 | °C | |

Unit: mm



Weight: 0.36 g (typ.)



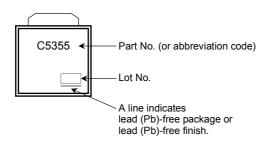
Weight: 0.36 g (typ.)



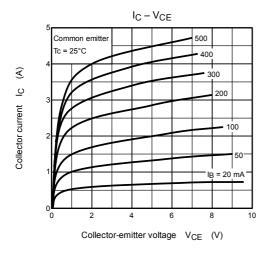
Electrical Characteristics (Ta = 25°C)

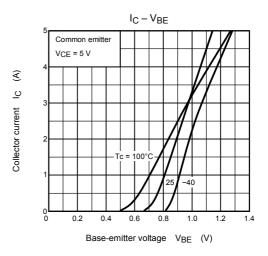
| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------------|--------------|-----------------------|---|-----|------|-----|------|
| Collector cut-off current | | I _{CBO} | V _{CB} = 480 V, I _E = 0 | _ | _ | 100 | μΑ |
| Emitter cut-off current | | I _{EBO} | V _{EB} = 7 V, I _C = 0 | _ | _ | 10 | μΑ |
| Collector-base breakdown voltage | | V (BR) CBO | I _C = 1 mA, I _E = 0 | 600 | _ | _ | V |
| Collector-emitter breakdown voltage | | V (BR) CEO | I _C = 10 mA, I _B = 0 | 400 | _ | _ | V |
| DC current gain | | h _{FE (1)} | V _{CE} = 5 V, I _C = 1 mA | 12 | _ | _ | |
| | | h _{FE (2)} | V _{CE} = 5 V, I _C = 0.5 A | 20 | _ | 65 | |
| Collector-emitter saturation voltage | | V _{CE (sat)} | I _C = 2 A, I _B = 0.25 A | _ | _ | 1.0 | V |
| Base-emitter saturation voltage | | V _{BE} (sat) | I _C = 2 A, I _B = 0.25 A | _ | _ | 1.3 | V |
| Switching time S | Rise time | t _r | 20 μs | _ | _ | 0.5 | |
| | Storage time | t _{stg} | | _ | _ | 2.0 | μs |
| | Fall time | t _f | I _{B1} = 0.25 A, I _{B2} = −0.5 A DUTY CYCLE ≤ 1% | _ | _ | 0.3 | |

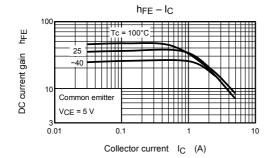
Marking

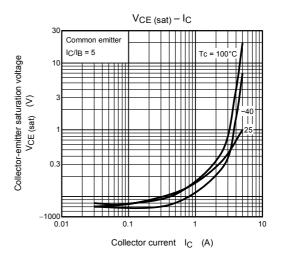


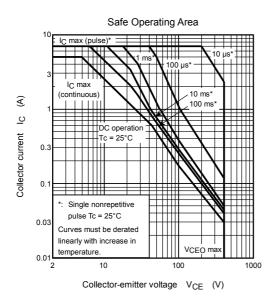
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Handbook" etc..

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